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May 2013

FDC8602

Dual N-Channel Shielded Gate PowerTrench® MOSFET 100 V, 1.2 A, 350 m Ω

Features

- Shielded Gate MOSFET Technology
- Max $r_{DS(on)}$ = 350 m Ω at V_{GS} = 10 V, I_D = 1.2 A
- Max $r_{DS(on)}$ = 575 m Ω at V_{GS} = 6 V, I_D = 0.9 A
- High performance trench technology for extremely low r_{DS(on)}
- High power and current handling capability in a widely used surface mount package
- Fast switching speed
- 100% UIL Tested
- RoHS Compliant

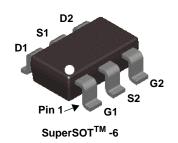


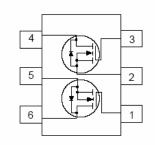
General Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench® process that incorporates Shielded Gate technology. This process has been optimized for r_{DS(on)}, switching performance and ruggedness.

Applications

- Load Switch
- Synchronous Rectifier





MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

Symbol	Parameter		Ratings	Units
V_{DS}	Drain to Source Voltage		100	V
V_{GS}	Gate to Source Voltage		±20	V
	Drain Current -Continuous	(Note 1a)	1.2	Α
'D	-Pulsed		5	Α
E _{AS}	Single Pulse Avalanche Energy	(Note 3)	1.5	mJ
Б	Power Dissipation	(Note 1a)	0.96	W
P_{D}	Power Dissipation	(Note 1b)	0.69	VV
T _J , T _{STG}	Operating and Storage Junction Temperature Range		-55 to +150	°C

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance, Junction to Case	60	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (Note 1a)	130	C/VV

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
.862	FDC8602	SSOT-6	7 "	8 mm	3000 units

Electrical Characteristics $T_J = 25$ °C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	cteristics					
BV _{DSS}	Drain to Source Breakdown Voltage	$I_D = 250 \mu A, V_{GS} = 0 V$	100			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	I_D = 250 μ A, referenced to 25 °C		73		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 80 V, V _{GS} = 0 V			1	μΑ
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA

On Characteristics

V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$	2	3.2	4	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	I_D = 250 μ A, referenced to 25 °C		-8		mV/°C
		V _{GS} = 10 V, I _D = 1.2 A		285	350	
r _{DS(on)}	20(611)	$V_{GS} = 6 \text{ V}, I_D = 0.9 \text{ A}$		409	575	mΩ
		$V_{GS} = 10 \text{ V}, I_D = 1.2 \text{ A}, T_J = 125 ^{\circ}\text{C}$		489	600	
g _{FS}	Forward Transconductance	V _{DS} = 10 V, I _D = 1.2 A		1.3		S

Dynamic Characteristics

C _{iss}	Input Capacitance	V 50 V V 0 V	53	70	pF
C _{oss}	Output Capacitance	$V_{DS} = 50 \text{ V}, V_{GS} = 0 \text{ V},$ $f = 1MHz$	17	25	pF
C _{rss}	Reverse Transfer Capacitance	1 – 1101112	0.8	5	pF
R_g	Gate Resistance		1.6		Ω

Switching Characteristics

t _{d(on)}	Turn-On Delay Time		3.5	10	ns
t _r	Rise Time	$V_{DD} = 50 \text{ V}, I_D = 1.2 \text{ A},$	1.7	10	ns
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = 10 \text{ V}, R_{GEN} = 6 \Omega$	5.4	11	ns
t _f	Fall Time		2.3	10	ns
$Q_{g(TOT)}$	Total Gate Charge	V _{GS} = 0 V to 10 V	1.2	2	nC
$Q_{g(TOT)}$	Total Gate Charge	$V_{GS} = 0 \ V \text{ to 5 } V$ $V_{DD} = 50 \ V,$	0.6	1	nC
Q_{gs}	Gate to Source Charge	I _D = 1.2 A	0.4		nC
Q _{gd}	Gate to Drain "Miller" Charge		0.4		nC

Drain-Source Diode Characteristics

V_{SD}	Source-Drain Diode Forward Voltage	V _{GS} = 0 V, I _S = 1.2 A (Note 2)		0.86	1.3	V
t _{rr}	Reverse Recovery Time	I _F = 1.2 A, di/dt = 100 A/μs		27	43	ns
Q _{rr}	Reverse Recovery Charge			12	21	nC

1. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design.



a) 130 °C/W when mounted on a 1 in² pad of 2 oz copper



b) 180 °C/W when mounted on a $minimum\,pad\,of\,2\,oz\,copper$

- 2. Pulse Test: Pulse Width < 300 μ s, Duty cycle < 2.0%.
- 3. Starting T $_J$ = 25 °C; N-ch: L = 3 mH, I $_{AS}$ = 1 A, V $_{DD}$ = 100 V, V $_{GS}$ = 10 V.

Typical Characteristics T_J = 25 °C unless otherwise noted

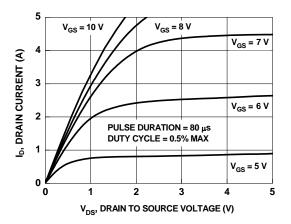


Figure 1. On Region Characteristics

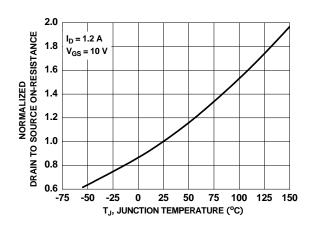


Figure 3. Normalized On Resistance vs Junction Temperature

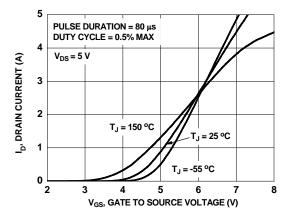


Figure 5. Transfer Characteristics

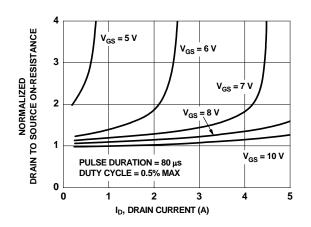


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

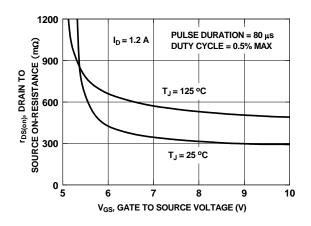


Figure 4. On-Resistance vs Gate to Source Voltage

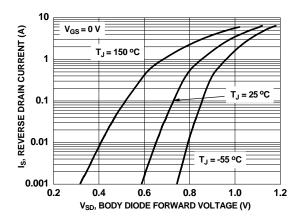


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

Typical Characteristics $T_J = 25$ °C unless otherwise noted

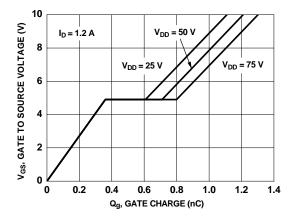


Figure 7. Gate Charge Characteristics

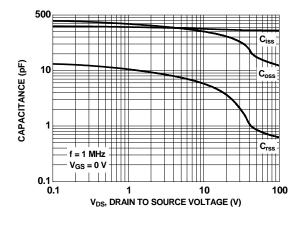


Figure 8. Capacitance vs Drain to Source Voltage

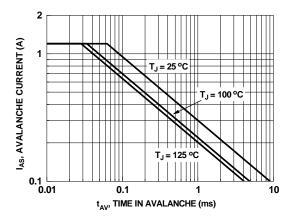


Figure 9. Unclamped Inductive Switching Capability

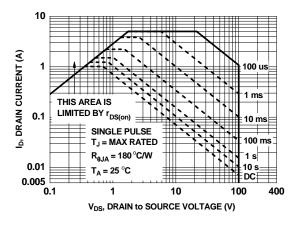


Figure 10. Forward Bias Safe Operating Area

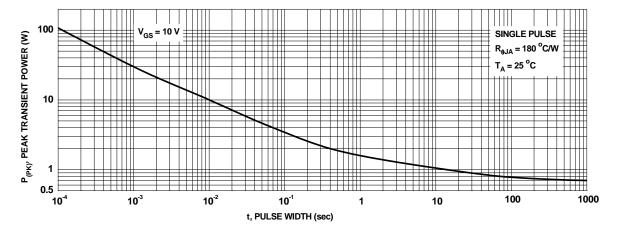


Figure 11. Single Pulse Maximum Power Dissipation

Typical Characteristics $T_J = 25$ °C unless otherwise noted

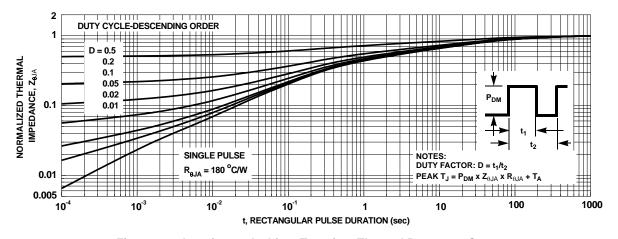


Figure 12. Junction-to-Ambient Transient Thermal Response Curve

Dimensional Outline and Pad Layout SYMM E 0.95 0.95 3.00 2.80 MA 1.00 MIN 4 В 3.00 2.60 2.60 1.70 1.50 3 0.95 0.70 MIN-◆ 0.20(M) C A B 1.90 LAND PATTERN RECOMMENDATION (0.30) -SEE DETAIL A 1.10 MAX 1.00 0.70 C 0.10 △ 0.10 C NOTES: UNLESS OTHERWISE SPECIFIED GAGE PLANE THIS PACKAGE CONFORMS TO JEDEC MO-193. VAR. AA, ISSUE C, DATED JANUARY 2000. ALL DIMENSIONS ARE IN MILLIMETERS. 0.25 0.55 0.35 SEATING PLANE -0.60 REF DETAIL A SCALE: 50X MA06AREVD





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